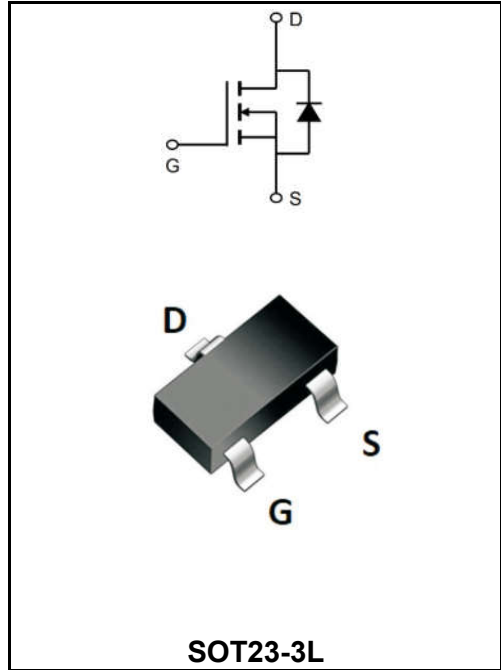


30V N-CHANNEL ENHANCEMENT MODE MOSFET

MAIN CHARACTERISTICS

I_D	8.0A
V_{DSS}	30V
R_{DS(on)-typ(@V_{GS}=10V)}	< 20mΩ (Type:15 mΩ)



Application

- ◆ Lithium battery protection
- ◆ Wireless impact
- ◆ Mobile phone fast charging



Product Specification Classification

Part Number	Package	Marking	Pack
YFW3404MI	SOT23-3L	3404	3000PCS/Tape

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbols	Value	Units
Drain-Source Voltage	V _{DS}	30	V
Gate - Source Voltage	V _{GS}	±20	V
Continuous Drain Current @T _A =25°C	I _D	8	A
Continuous Drain Current @T _A =70°C	I _D	4.9	A
Pulsed Drain Current ²	I _{DM}	20	A
Total Power Dissipation ³ @T _A =25°C	P _D	1	W
Storage Temperature Range	T _{STG}	-55 to +150	°C
Operating Junction Temperature Range	T _J	-55 to +150	°C
Thermal Resistance Junction-ambient ¹	R _{θJA}	125	°C/W
Thermal Resistance Junction-Ambient 1 (t ≤10s)	R _{θJA}	85	°C/W

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	BV_{DSS}	30	32	-	V
BVDSS Temperature Coefficient	Reference to 25°C , $I_D=1mA$	$\Delta BV_{DSS}/\Delta T_J$	-	0.029	-	V/°C
Static Drain-Source On-Resistance ²	$V_{GS}=10V, I_D=5.8A$	$R_{DS(ON)}$	-	15	20	mΩ
	$V_{GS}=4.5V, I_D=5A$		-	25	32	
Gate -Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	$V_{GS(th)}$	1.2	1.6	2.5	V
$V_{GS(th)}$ Temperature Coefficient		$\Delta V_{GS(th)}$	-	-2.82	-	mV/°C
Drain-Source Leakage Current	$V_{DS}=24V, V_{GS}=0V, T_J=25^\circ C$	I_{DSS}	-	-	1	μA
	$V_{DS}=24V, V_{GS}=0V, T_J=55^\circ C$		-	-	5	
Gate -Source Leakage Current	$V_{GS}=\pm 12V, V_{DS}=0V$	I_{GSS}	-	-	±100	nA
Forward Transconductance	$V_{DS}=5V, I_D=5A$	g_{fs}	-	25	-	S
Gate Resistance	$V_{DS}=0V, V_{GS}=0V, f=1MHz$	R_g	-	1.5	-	Ω
Total Gate Charge(4.5V)	$V_{DS}=15V$ $V_{GS}=4.5V$ $I_D=5.8A$	Q_g	-	11.5	-	nC
Gate-Source Charge		Q_{gs}	-	1.6	-	
Gate-Drain Charge		Q_{gd}	-	2.9	-	
Turn-on delay time	$V_{DD}=15V$ $V_{GS}=10V$ $R_G=3\Omega$ $I_D=5A$	$t_{d(on)}$	-	5	-	ns
Rise Time		T_r	-	47	-	
Turn-Off Delay Time		$t_{d(OFF)}$	-	26	-	
Fall Time		t_f	-	8	-	
Input Capacitance	$V_{DS}=15V$ $V_{GS}=0V$ $f=1.0MHz$	C_{iss}	-	860	-	μF
Output Capacitance		C_{oss}	-	84	-	
Reverse Transfer Capacitance		C_{rss}	-	70	-	
Continuous Source Current ^{1,4}	$V_G=V_D=0V, \text{Force Current}$	I_S	-	-	5.8	A
Diode Forward Voltage ²	$V_{GS}=0V, I_S=1A, T_J=25^\circ C$	V_{SD}	-	-	1.2	V

Note :

- 1、 The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.
- 2、 The data tested by pulsed , pulse width $\cong 300\mu s$, duty cycle $\cong 2\%$
- 3、 The power dissipation is limited by 150°C junction temperature
- 4、 The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.

Ratings and Characteristic Curves

Typical Characteristics

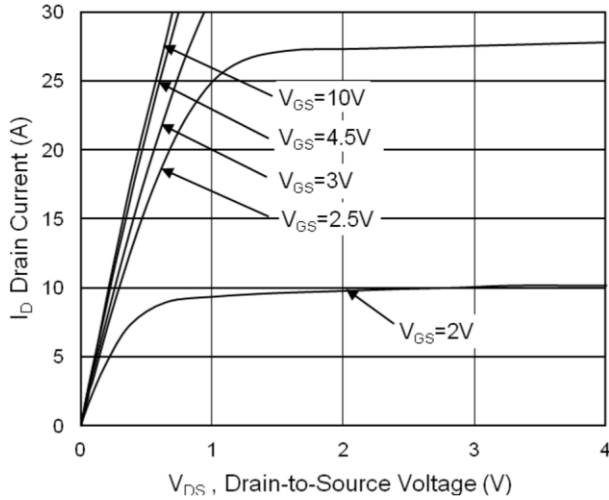


Fig.1 Typical Output Characteristics

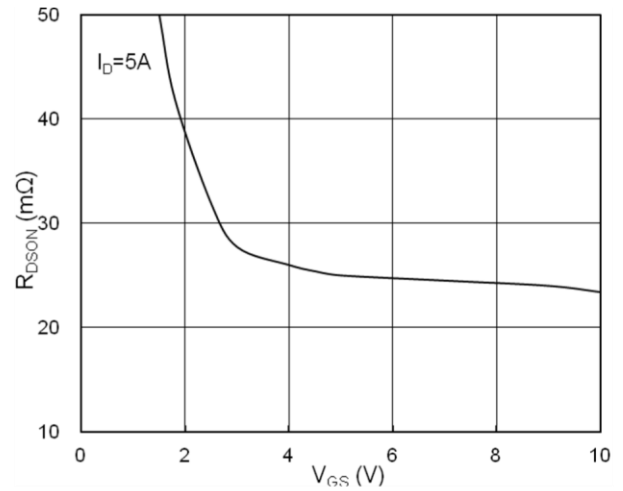


Fig.2 On-Resistance vs. Gate-Source

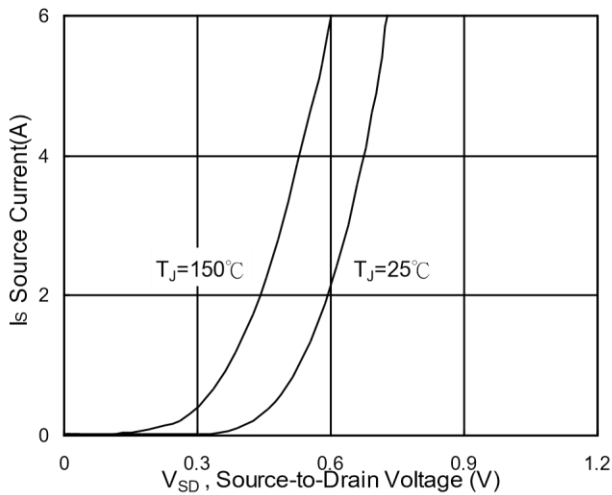


Fig.3 Forward Characteristics Of Reverse

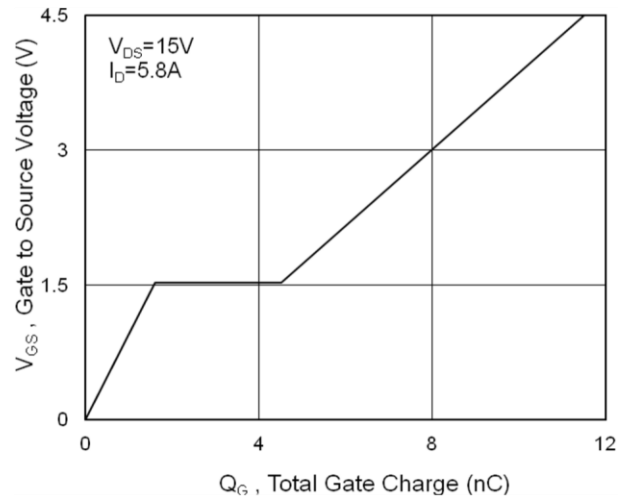
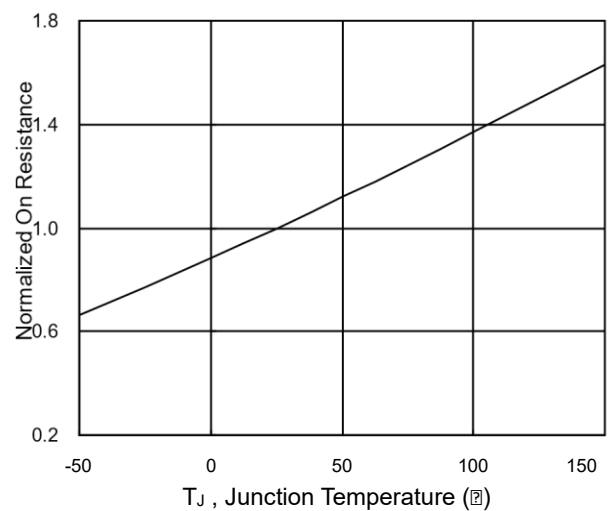
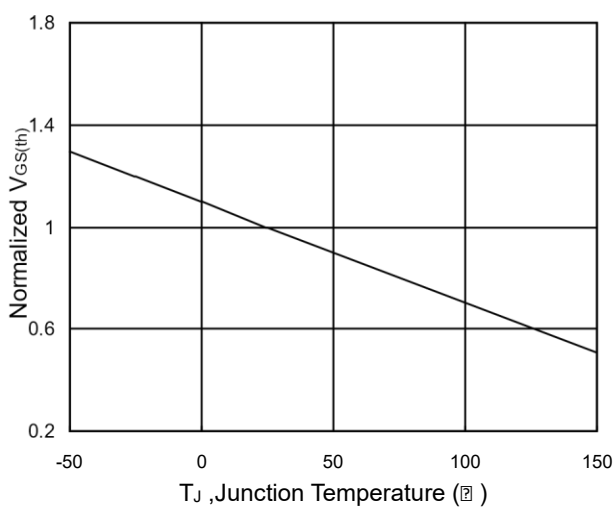


Fig.4 Gate-Charge Characteristics



Ratings and Characteristic Curves

Fig.5 Normalized $V_{GS(th)}$ vs. T_J

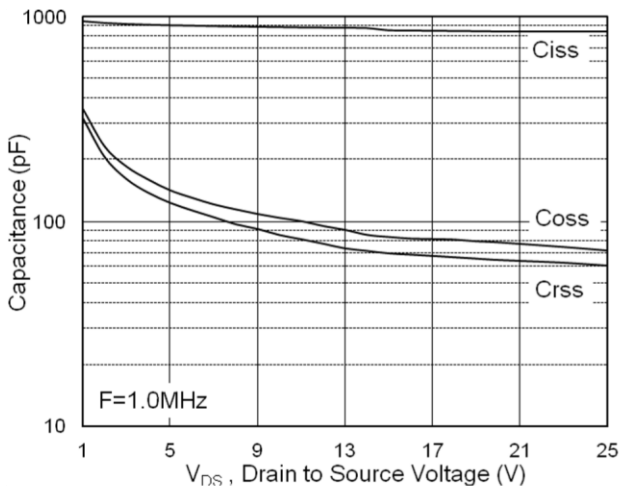


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

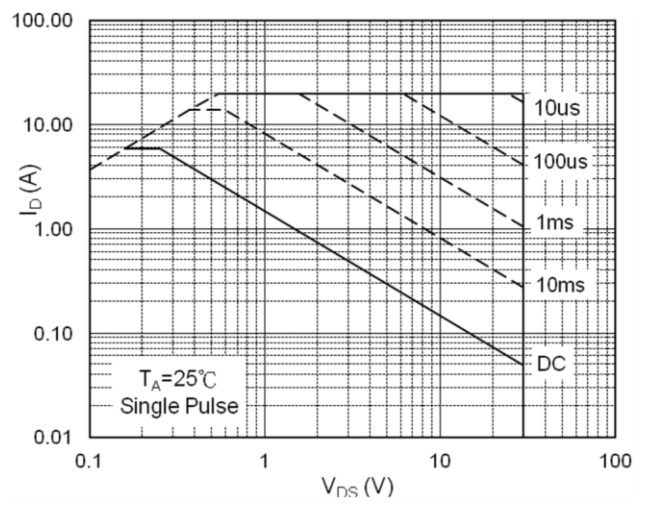


Fig.7 Capacitance

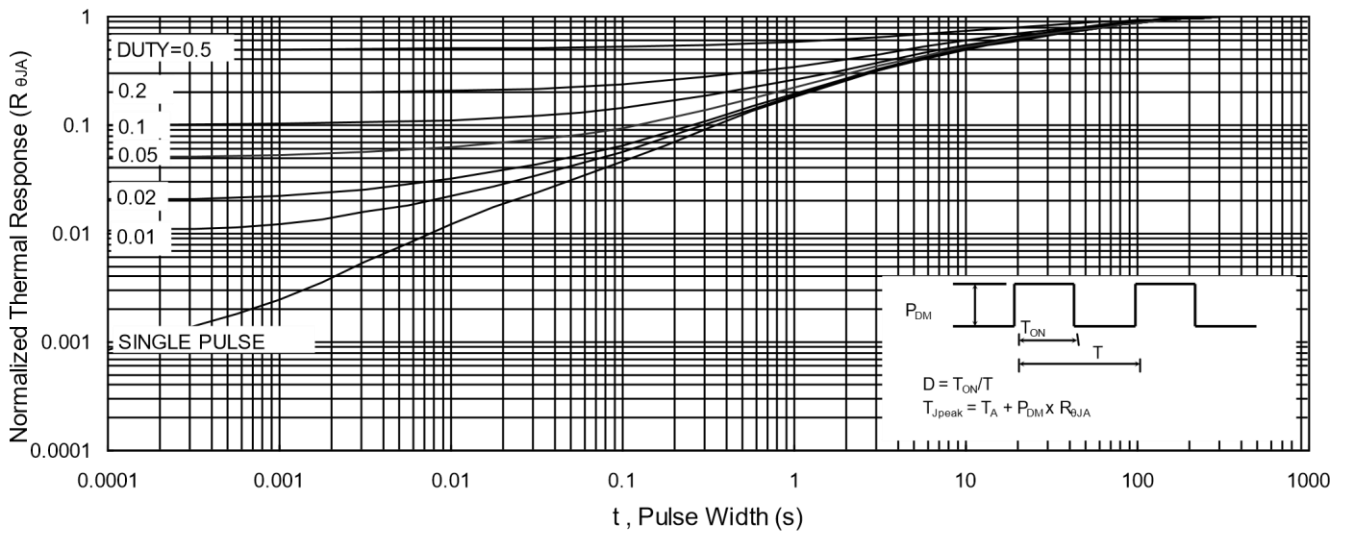


Fig.8 Safe Operating Area

Fig.9 Normalized Maximum Transient Thermal Impedance

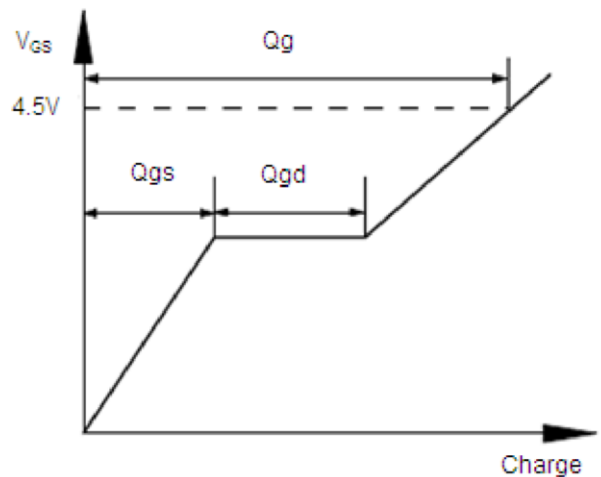
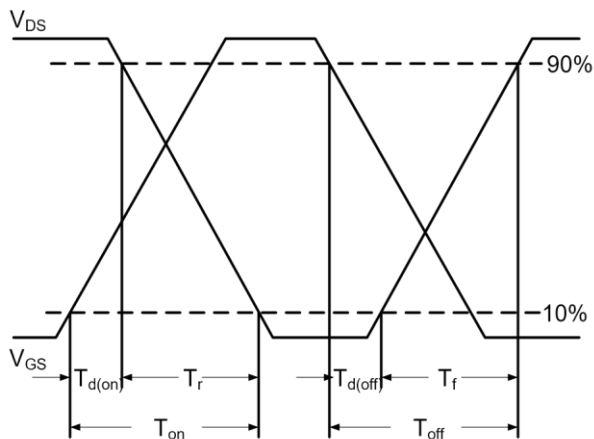
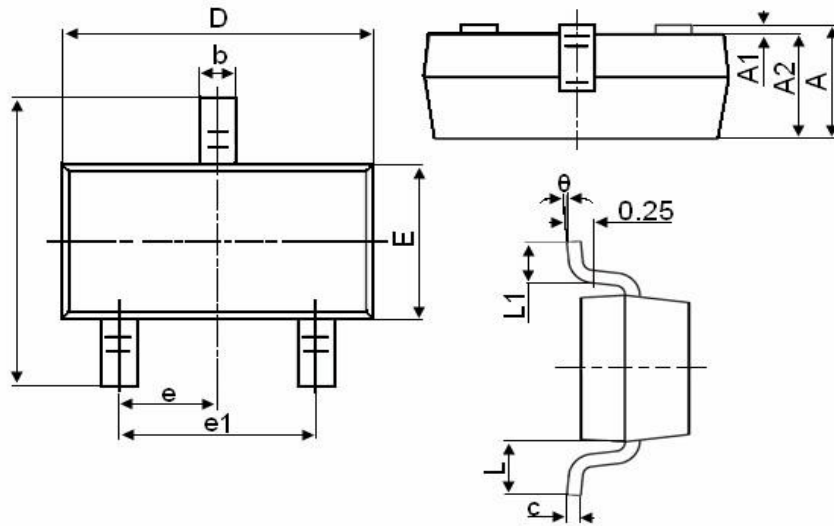


Fig.10 Switching Time Waveform

Fig.11 Gate Charge Waveform

SOT23-3L



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
theta	0°	8°

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[DMN2990UFB-7B](#) [SSM3K35CT,L3F](#) [IPLK60R1K0PFD7ATMA1](#) [2N7002W-G](#) [MCAC30N06Y-TP](#) [IPWS65R035CFD7AXKSA1](#)
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